HALOGEN

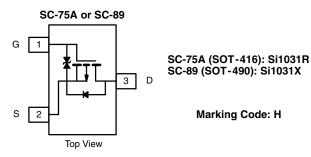
FREE





P-Channel 20 V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (mA)			
- 20	8 at V _{GS} = - 4.5 V	- 150			
	12 at V _{GS} = - 2.5 V	- 125			
	15 at V _{GS} = - 1.8 V	- 100			
	20 at V _{GS} = - 1.5 V	- 30			



Ordering Information:

Si1031R-T1-GE3 (SC-75A, Lead (Pb)-free and Halogen-free) Si1031X-T1-GE3 (SC-89, Lead (Pb)-free and Halogen-free)

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- · High-Side Switching
- Low On-Resistance: 8 Ω
- Low Threshold: 0.9 V (typ.)
- Fast Switching Speed: 45 ns
- TrenchFET[®] Power MOSFETs: 1.5 V Rated
- ESD Protected: 2000 V
- · Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories
- Battery Operated Systems
- Power Supply Converter Circuits
- · Load/Power Switching Cell Phones, Pagers

BENEFITS

- · Ease in Driving Switches
- · Low Offset (Error) Voltage
- Low-Voltage Operation
- High-Speed Circuits
- Low Battery Voltage Operation

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)							
Parameter			Si1031R		Si1031X		
		Symbol	5 s	Steady State	5 s	Steady State	Unit
Drain-Source Voltage	V_{DS}	- 20				V	
Gate-Source Voltage		V_{GS}	± 6				
Continuous Dunin Comment /T 150 °C\ ²	T _A = 25 °C	- I _D	- 150	- 140	- 165	- 155	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 85 °C		- 110	- 100	- 150	- 125	
Pulsed Drain Current ^a		I _{DM}	- 500 - 600		600	- mA	
Continuous Source Current (Diode Conduction) ^a		I _S	- 250	- 200	- 340	- 240	
	T _A = 25 °C	В	280	250	340	300	mW
Maximum Power Dissipation ^a	T _A = 85 °C	P _D	145	130	170	150	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150				°C
Gate-Source ESD Rating (HBM, Method 3015)		ESD	2000				V

Notes:

a. Surface mounted on FR4 board.

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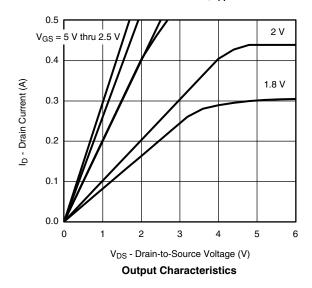
SPECIFICATIONS (T _A = 25 °C, unless otherwise noted)								
Parameter	Symbol	Test Conditions	Min.	Typ. ^a	Max.	Unit		
Static								
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 0.40		- 1.2	V		
Oata Barket askana		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 2.8 \text{ V}$		± 0.5	± 1.0	μΑ		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$		± 1.0	± 2.0			
Zara Cata Valtara Drain Current	1	V _{DS} = - 16 V, V _{GS} = 0 V		- 1	- 500	nA		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 16 V, V _{GS} = 0 V, T _J = 85 °C			- 10	μΑ		
On-State Drain Current ^a	I _{D(on)}	V _{DS} = - 5 V, V _{GS} = - 4.5 V	- 200			mA		
	R _{DS(on)}	V _{GS} = - 4.5 V, I _D = - 150 mA			8	Ω		
		V _{GS} = - 2.5 V, I _D = - 125 mA			12			
Drain-Source On-State Resistance ^a		V _{GS} = - 1.8 V, I _D = - 100 mA			15			
		V _{GS} = - 1.5 V, I _D = - 30 mA			20			
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 10 V, I _D = 150 mA		0.4		S		
Diode Forward Voltage ^a	V_{SD}	I _S = - 150 mA, V _{GS} = 0 V			- 1.2	V		
Dynamic ^b								
Total Gate Charge	Q_g			1500				
Gate-Source Charge	Q_{gs}	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -150 \text{ mA}$		150		рC		
Gate-Drain Charge	Q_{gd}			450				
Turn-On Delay Time	t _{d(on)}				55			
Rise Time	t _r	V_{DD} = - 10 V, R_L = 65 Ω			30	ns		
Turn-Off Delay Time	t _{d(off)}	$I_D \cong$ - 150 mA, $V_{GEN} =$ - 4.5 V, $R_g = 10 \Omega$			60			
Fall Time	t _f				30			

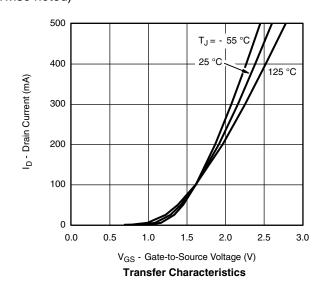
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

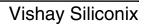
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



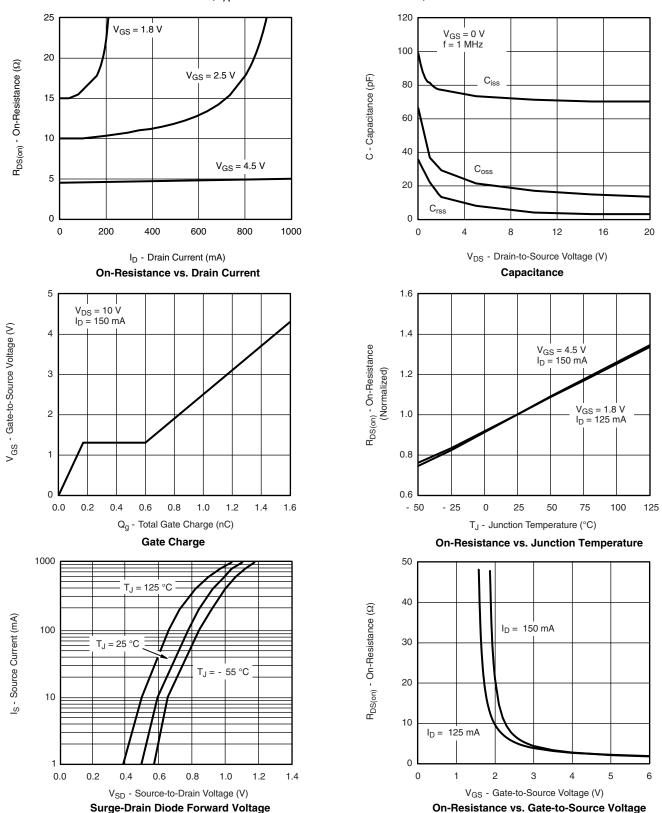








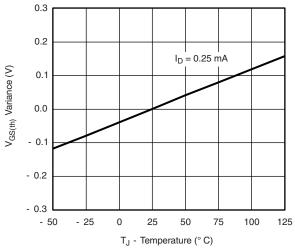
TYPICAL CHARACTERISTICS ($T_A = 25$ °C, unless otherwise noted)

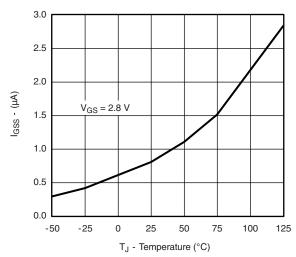


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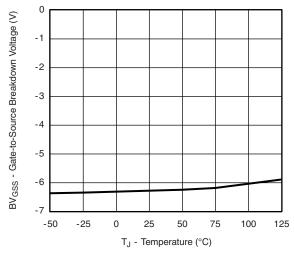
TYPICAL CHARACTERISTICS ($T_A = 25$ °C, unless otherwise noted)



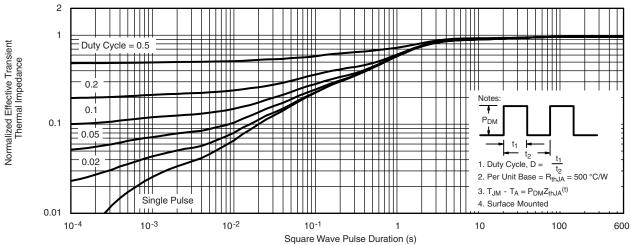


Threshold Voltage Variance vs. Temperature

I_{GSS} vs. Temperature



BV_{GSS} vs. Temperature

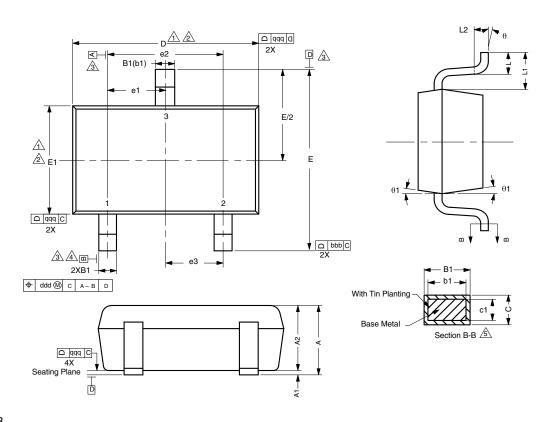


Normalized Thermal Transient Impedance, Junction-to-Ambient (SC-75A, Si1031R Only)

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71171.



SC-75A: 3 Leads



DWG: 5868

Notes

Dimensions in millimeters will govern.

1 Dimension D does not include mold flash, protrusions or gate burrs. Mold flash protrusions or gate burrs shall not exceed 0.10 mm per end. Dimension E1 does not include Interlead flash or protrusion. Interlead flash or protrusion shall not exceed 0.10 mm per side.

2. Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, tie bar burrs, gate burrs and interelead flash, but including any mismatch between the top and bottom of the plastic body.

Datums A, B and D to be determined 0.10 mm from the lead tip.

A Terminal positions are shown for reference only.

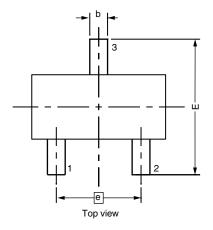
These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.

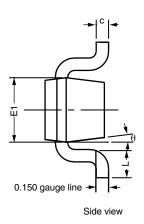
DIMENSIONS	TOLERANCES		
aaa	0.10		
bbb	0.10		
ccc	0.10		
ddd	0.10		

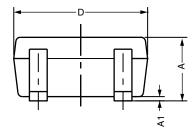
DIM.	N			
DIIVI.	MIN.	NOM.	MAX.	NOTE
Α	-	-	0.80	
A ₁	0.00	-	0.10	
A ₂	0.65	0.70	0.80	
B ₁	0.19	-	0.24	5
b ₁	0.17	-	0.21	
С	0.13	-	0.15	5
C ₁	0.10	-	0.12	5
D	1.48	1.575	1.68	1, 2
E	1.50	1.60	1.70	
E ₁	0.66	0.76	0.86	1, 2
e ₁				
e ₂				
e ₃	0.50 BSC			
L	0.15	0.205	0.30	
L ₁	0.40 ref.			
L ₂	0.15 BSC			
θ	0°	-	8°	
θ_1	4°	-	10°	

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For Samsung only







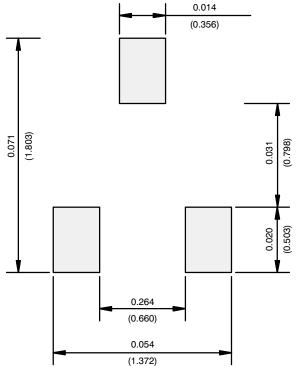
Notes

- (1) Millimeters will govern.
- (2) Dimension exclusive of mold gate burrs.
- (3) Dimension exclusive of mold flash and cutting burrs.

DIM.	MILLIMETERS			INCHES			
Dilvi.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
Α	0.60	0.70	0.80	0.024	0.028	0.031	
A1	0.00	0.05	0.10	0.000	0.002	0.004	
b	0.18	0.22	0.32	0.007	0.009	0.013	
С	0.11	0.13	0.21	0.004	0.005	0.008	
D	1.48	1.58	1.68	0.058	0.062	0.066	
E	1.50	1.60	1.70	0.059	0.063	0.067	
E1	0.66	0.76	0.86	0.026	0.030	0.034	
е	0.95	1.00	1.05	0.037	0.039	0.041	
L	0.22	0.32	0.42	0.009	0.013	0.017	
θ	4°	7°	10°	4°	7°	10°	



RECOMMENDED MINIMUM PADS FOR SC-75A: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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Revision: 02-Oct-12 Document Number: 91000

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